

Morphological Evolution of Neodymium Boride Nanowire Growth by Chemical Vapor Deposition

Gonghua Wang[†], Joseph R. Brewer[†], Jie Ying Chan[†], David R. Diercks[¶] and Chin Li Cheung^{†,}*

[†]Department of Chemistry and Nebraska Center for Materials and Nanoscience,

University of Nebraska-Lincoln, Lincoln, NE 68588-0304, and

[¶]Center for Advanced Research and Technology, University of North Texas, Denton, TX 76207.

* Corresponding author. Email: ccheung2@unl.edu

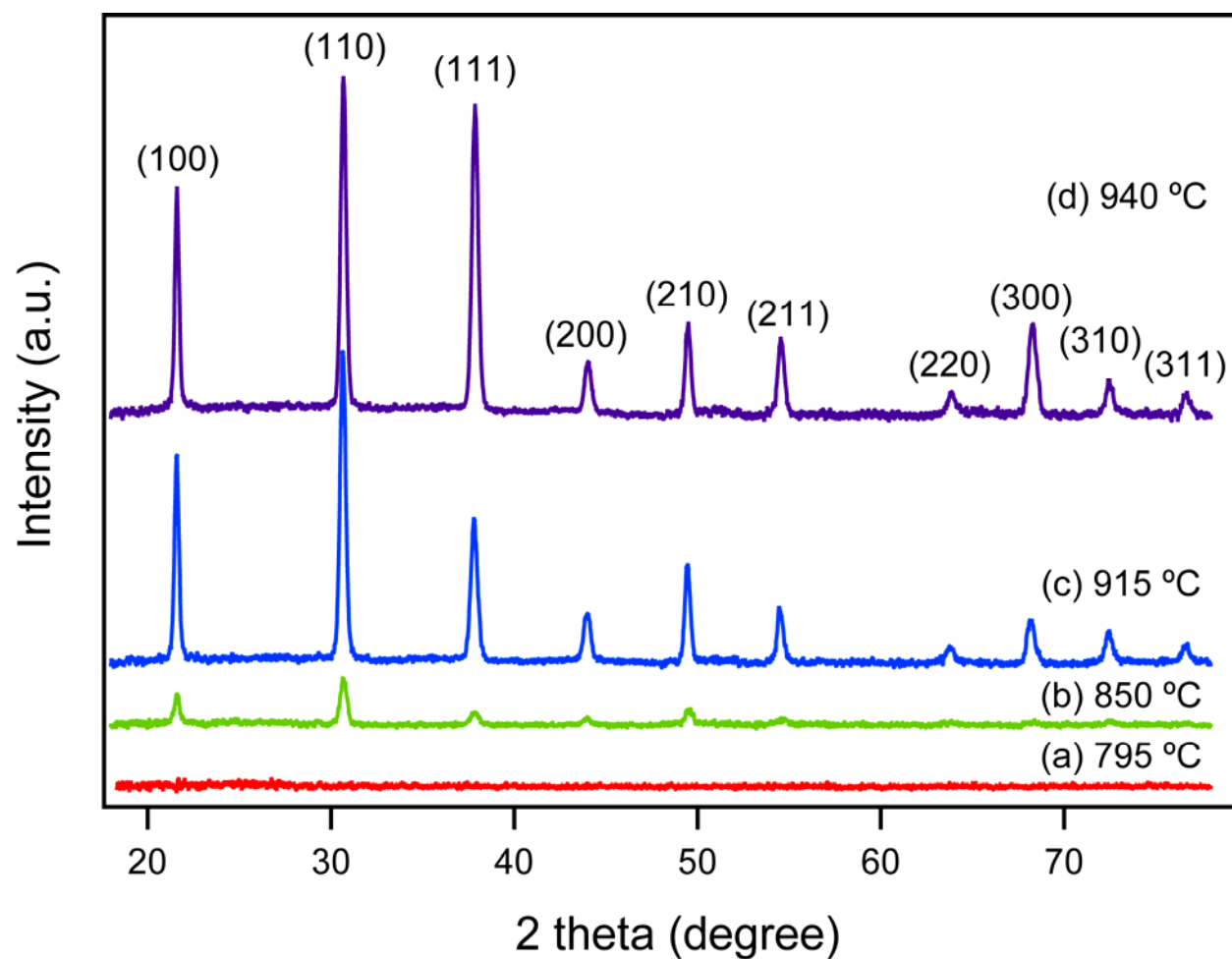


Figure S1. XRD spectra of *Sample 1, 2, 3 and 4* synthesized by chemical vapor deposition at (a) 795 °C, (b) 850 °C, (c) 915 °C and (d) 940 °C. The peaks attributing to NdB₆ phase are indexed in the figure.

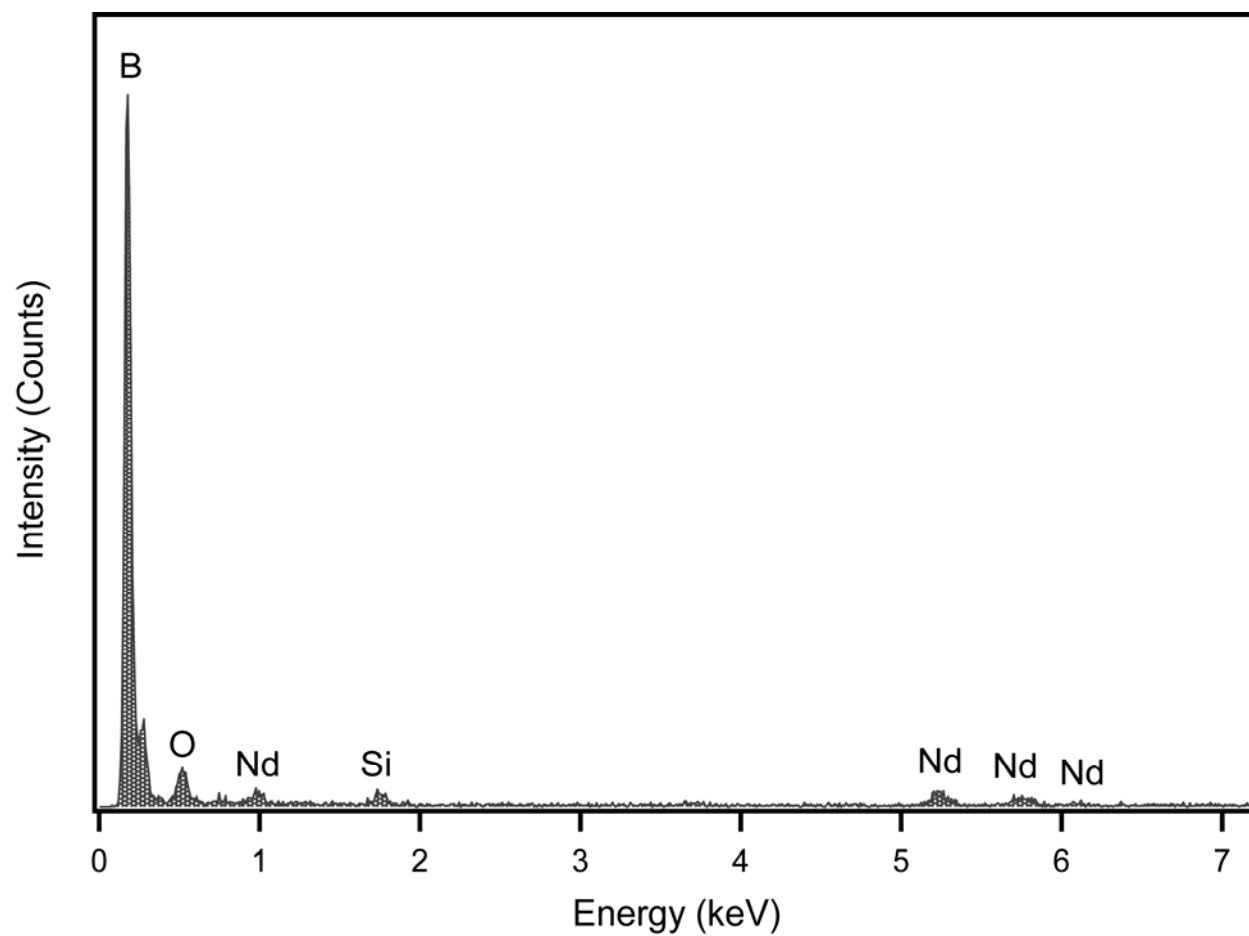


Figure S2. EDX spectrum of the nanowire synthesized at 795 °C (*Sample 1*) shown in Figure 2(a).

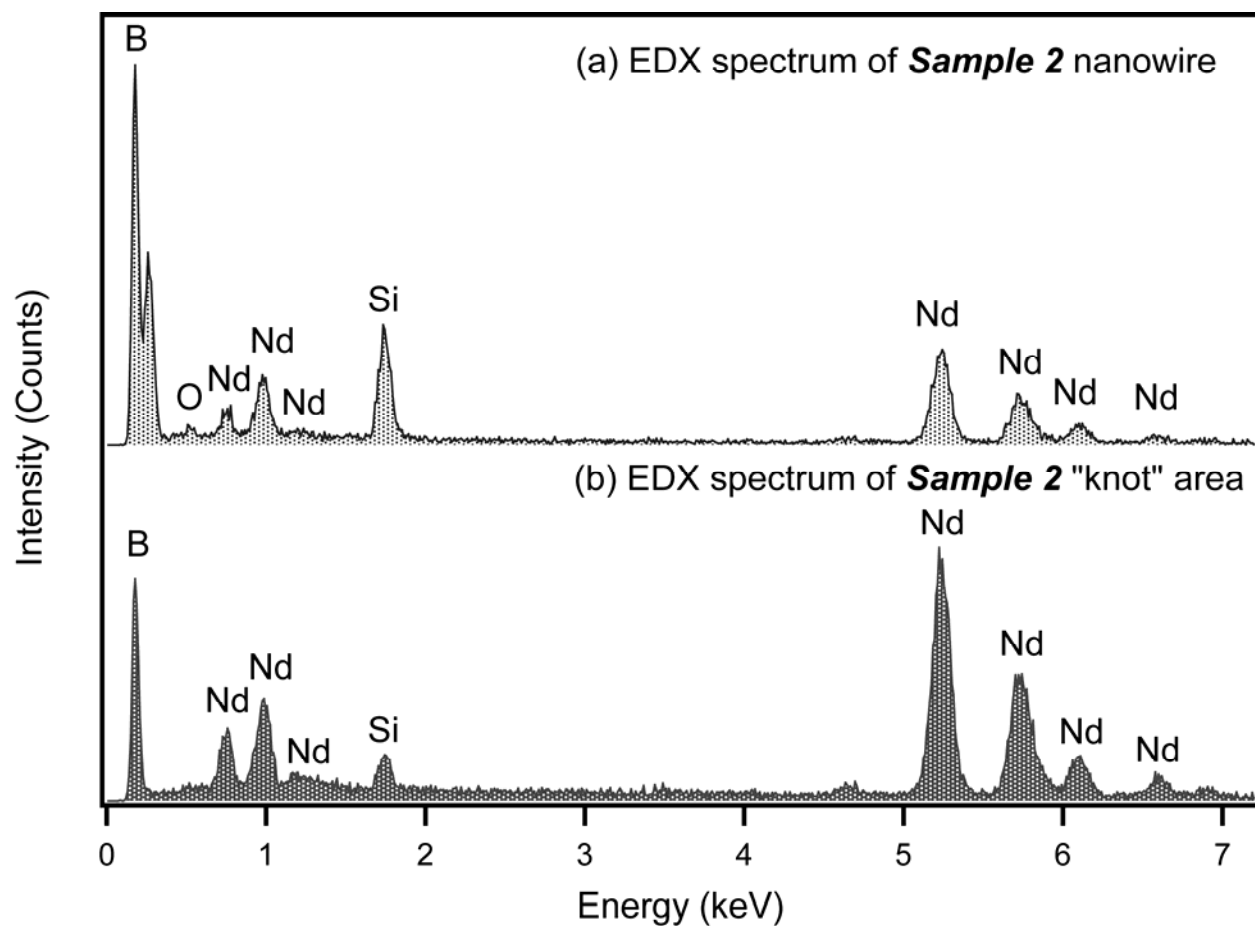


Figure S3. EDX spectra of (a) the bulk and (b) the “knot” area of the neodymium boride nanowire synthesized at 850 °C (**Sample 2**) shown in Figure 2(b).

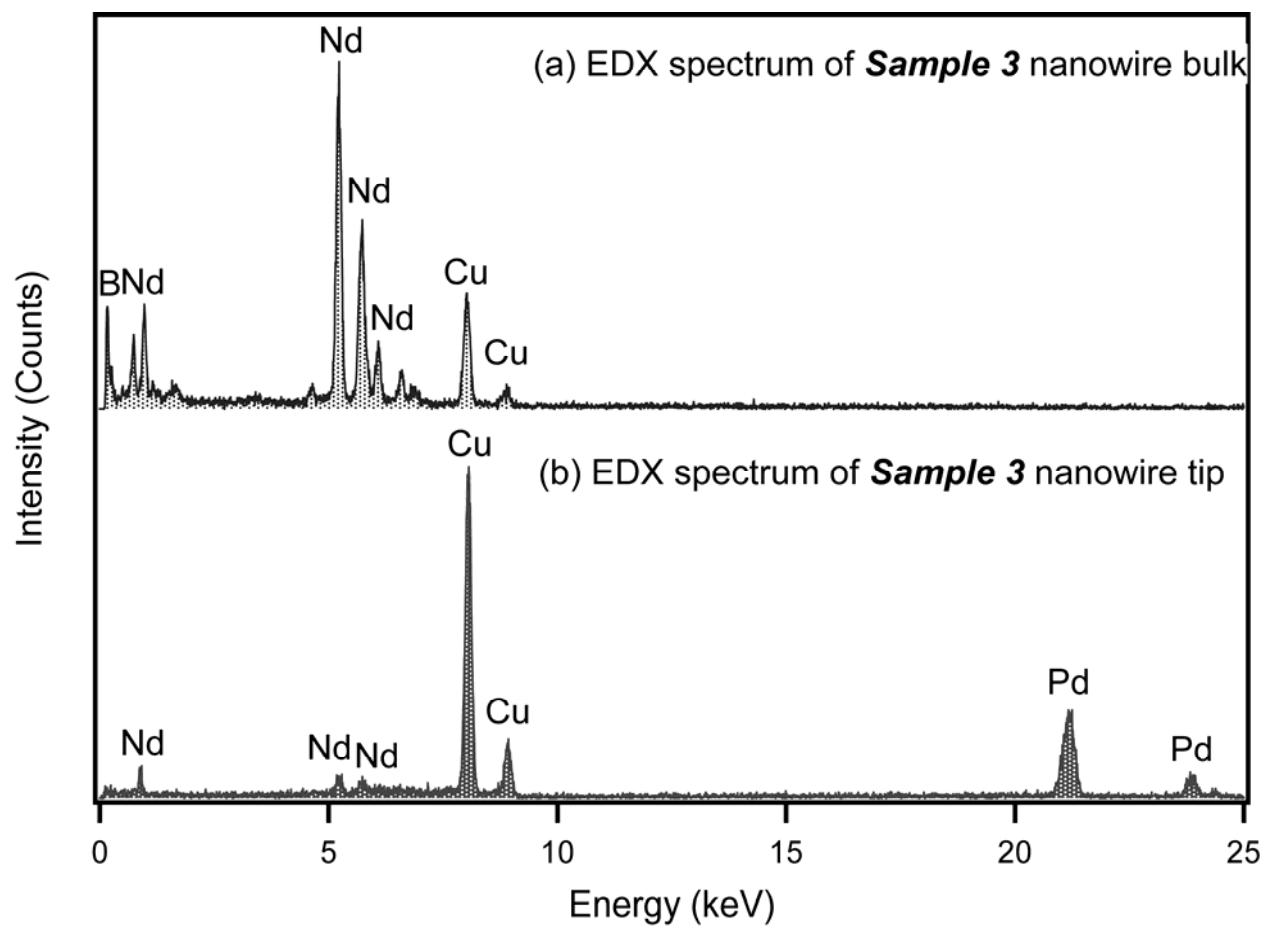


Figure S4. EDX spectra of (a) the bulk and (b) the tip particle of the neodymium boride nanowire synthesized at 915 °C (**Sample 3**) shown in Figure 2(c).

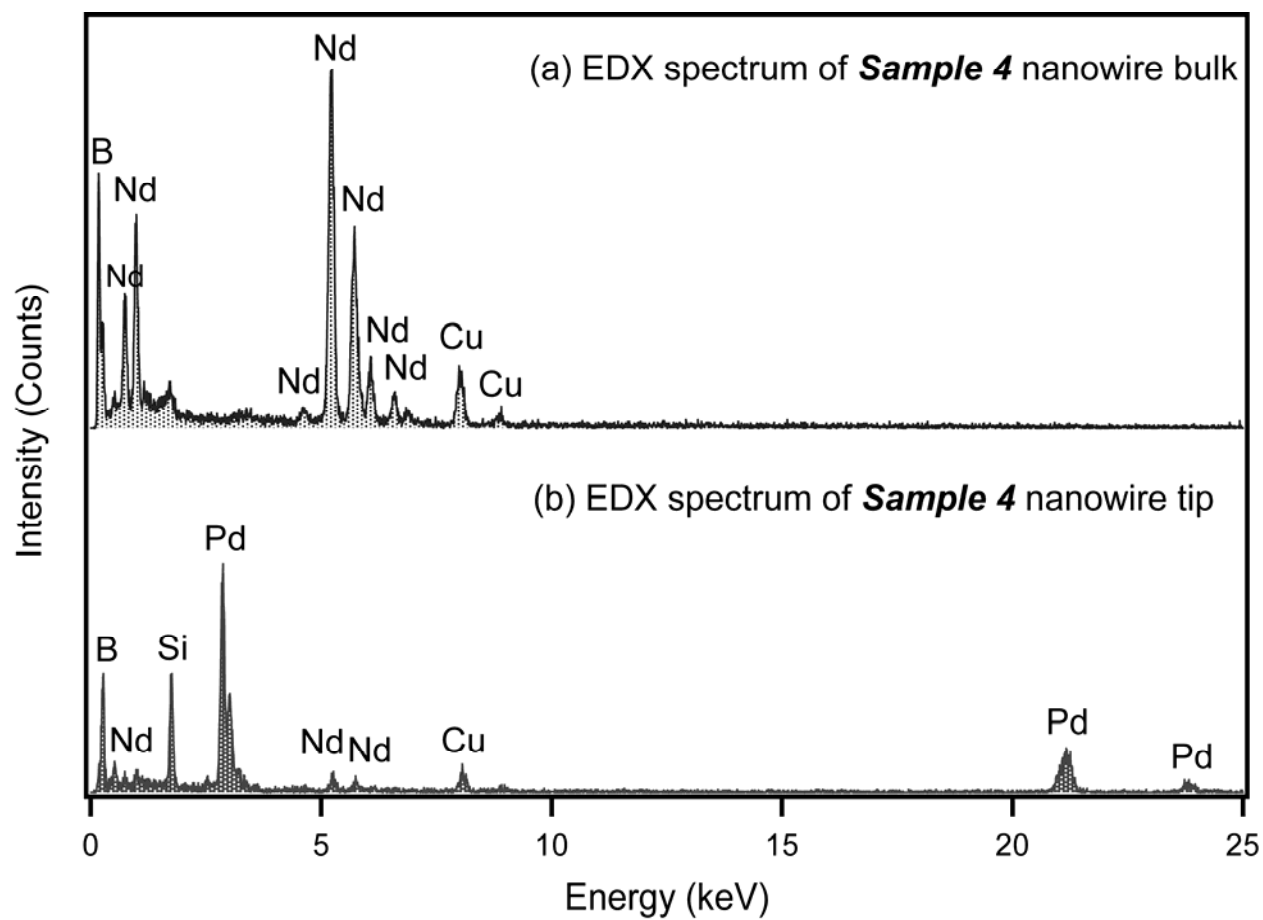


Figure S5. EDX spectra of (a) the bulk and (b) the tip particle of the neodymium boride nanowire synthesized at 940 °C (**Sample 4**) shown in Figure 2(d).

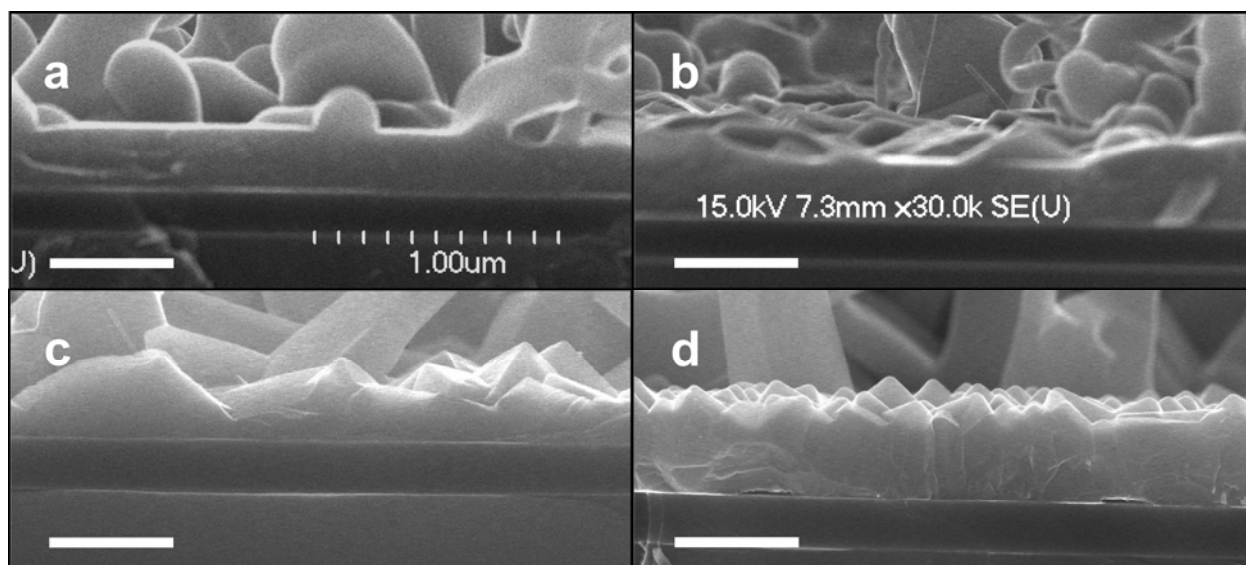


Figure S6. Cross-sectional view SEM images of films at the bottom of neodymium boride samples synthesized by chemical vapor deposition at (a) 795 °C, (b) 850 °C, (c) 915 °C and (d) 940 °C. The scale bars are 500 nm.